Nch 100V 120A Power MOSFET

| V_{DSS} | 100V |
|----------------------------|-------|
| R _{DS(on)} (Max.) | 5.8mΩ |
| I _D | ±120A |
| P _D | 178W |

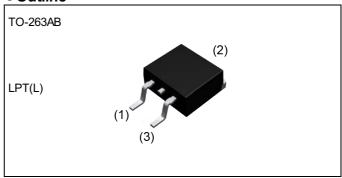
Features

- 1) Low on resistance
- 2) High power small mold package
- 3) Pb-free lead plating; RoHS compliant
- 4) UIS tested
- 5) Halogen free

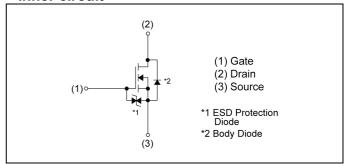
Application

Switching

Outline



Inner circuit



Packaging specifications

| ● Fackaç | Jing specifications | |
|----------|---------------------|------------------|
| | Packing | Embossed Tape |
| | Reel size (mm) | 330 |
| Type | Tape width (mm) | 24 |
| | Quantity (pcs) | 1000 |
| | Taping code | TLL |
| | Marking | RJ1P12BBD |

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

| Parameter | Symbol | Value | Unit | |
|-----------------------------------|-----------------------|--------------------|-------------|----|
| Drain - Source voltage | | V_{DSS} | 100 | V |
| Continuous drain current | V _{GS} = 10V | I _D *1 | ±120 | Α |
| Pulsed drain current | I _{DP} *2 | ±240 | Α | |
| Gate - Source voltage | V_{GSS} | ±20 | V | |
| Avalanche current, single pulse | | I _{AS} *3 | 40 | Α |
| Avalanche energy, single pulse | E _{AS} *3 | 125 | mJ | |
| Power dissipation | P _D *1 | 178 | W | |
| Junction temperature | T _j | 150 | °C | |
| Operating junction and storage te | mperature range | T _{stg} | -55 to +150 | °C |

●Thermal resistance

| Parameter | Symbol | Values | | | l limit |
|-------------------------------------|----------------------|--------|------|------|---------|
| Parameter | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - case | R _{thJC} *1 | - | 1 | 0.70 | °C/W |

● Electrical characteristics (T_a = 25°C)

| Daramatar | Curahal | Conditions | | Values | | Unit | |
|--|--|---|------|--------|------|-------|--|
| Parameter | Symbol Conditions | | Min. | Тур. | Max. | Oriit | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D = 1mA | 100 | - | - | V | |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_j} I_D = 1 \text{mA}$ referenced to 25°C | | - | 98.33 | - | mV/°C | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = 100V, V _{GS} = 0V | - | - | 10 | μA | |
| Gate - Source leakage current | I _{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | - | - | ±10 | μΑ | |
| Gate threshold voltage | $V_{GS(th)}$ | V _{DS} = 10V, I _D = 2.5mA | 2.0 | - | 4.0 | V | |
| Gate threshold voltage temperature coefficient | $\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$ | I _D = 1mA referenced to 25°C | - | -8.28 | - | mV/°C | |
| Static drain - source | D *4 | V _{GS} = 10V, I _D = 50A | - | 4.4 | 5.8 | m0 | |
| on - state resistance | R _{DS(on)} *4 | V _{GS} = 6.0V, I _D = 40A | - | 5.2 | 7.8 | mΩ | |
| Gate resistance | R_{G} | f = 1MHz, open drain | - | 2.6 | - | Ω | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = 5V, I _D = 40A | 30 | - | - | S | |

^{*1} T_c =25°C, Limited only by maximum temperature allowed.

^{*2} Pw≦10µs , Duty cycle≦1%

^{*3} L \simeq 0.10mH, V_{DD} = 50V, R_G = 25 Ω , Starting T_j = 25 $^{\circ}$ C Fig.3-1,3-2

^{*4} Pulsed

● Electrical characteristics (T_a = 25°C)

| Daramatar | Symbol Conditions | | Values | | | Unit | |
|------------------------------|------------------------|-----------------------------------|--------|------|------|------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 4170 | - | | |
| Output capacitance | C _{oss} | V _{DS} = 50V | - | 590 | - | pF | |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 130 | - | | |
| Turn - on delay time | t _{d(on)} *4 | $V_{DD} \simeq 50V, V_{GS} = 10V$ | - | 37 | - | | |
| Rise time | t _r *4 | I _D = 50A | 1 | 33 | 1 | no | |
| Turn - off delay time | t _{d(off)} *4 | $R_L \simeq 1.0\Omega$ | - | 125 | - | ns | |
| Fall time | t _f *4 | $R_G = 10\Omega$ | - | 54 | - | | |

• Gate charge characteristics $(T_a = 25^{\circ}C)$

| Daramatar | Cymah al | Canditiana | | Values | | | Unit |
|----------------------|--------------------|-----------------------|-----------------------|--------|------|-------|------|
| Parameter | Symbol Conditions | | Min. | Тур. | Max. | Offic | |
| Total gate charge | O *4 | | V _{GS} = 10V | - | 80.0 | 1 | |
| Total gate charge | Q _g *4 | V _{DD} ≃ 50V | | - | 51.0 | - | »C |
| Gate - Source charge | Q _{gs} *4 | I _D = 50A | V _{GS} = 6V | - | 24.0 | - | nC |
| Gate - Drain charge | Q _{gd} *4 | | | - | 17.5 | - | |

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

| Daramatar | Cumbal | Conditions | Values | | | Lloit |
|----------------------------|--------------------|--|--------|------|------|-------|
| Parameter | Symbol Conditions | | Min. | Тур. | Max. | Unit |
| Continuous forward current | I _S | T _a = 25°C | - | - | 120 | Α |
| Pulse forward current | I _{SP} *2 | 1 _a - 25 C | - | - | 240 | Α |
| Forward voltage | V _{SD} *4 | V _{GS} = 0V, I _S = 40A | - | - | 1.2 | V |
| Reverse recovery time | t _{rr} *4 | I _S = 50A, V _{GS} =0V | - | 67 | - | ns |
| Reverse recovery charge | Q _{rr} *4 | di/dt = 100A/µs | - | 225 | - | nC |

Fig.1 Power Dissipation Derating Curve

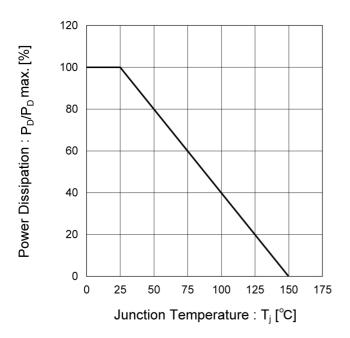


Fig.2 Maximum Safe Operating Area

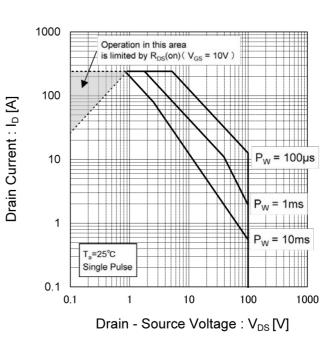


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

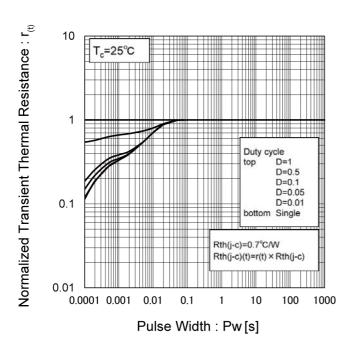


Fig.4 Single Pulse Maximum Power dissipation

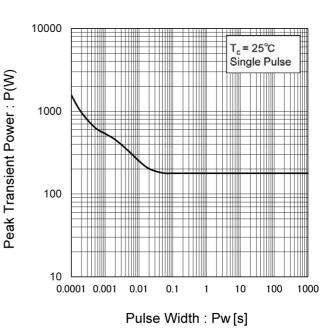


Fig.5 Typical Output Characteristics(I)

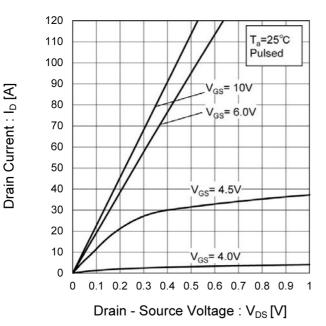
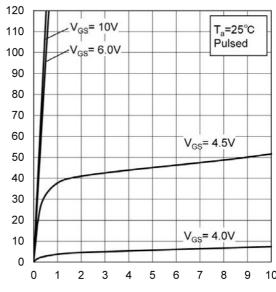


Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.7 Breakdown Voltage vs.

Junction Temperature

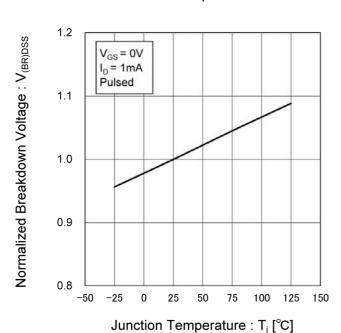


Fig.8 Typical Transfer Characteristics

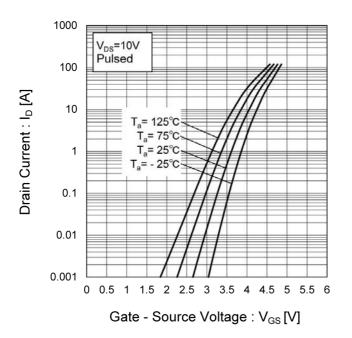


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

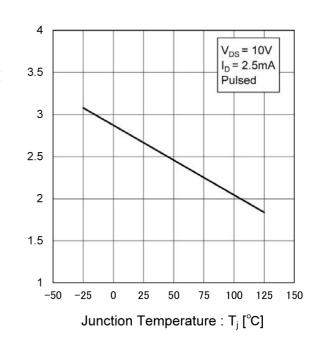
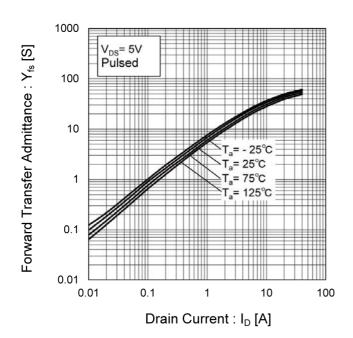


Fig.10 Forward Transfer Admittance vs.
Drain Current



Gate Threshold Voltage: VGS(th) [V]

Fig.11 Drain Current Derating Curve

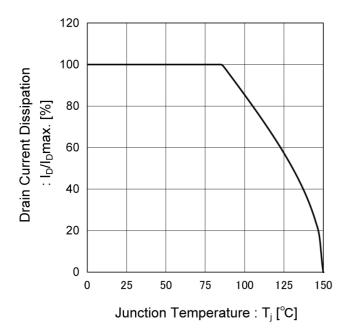


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

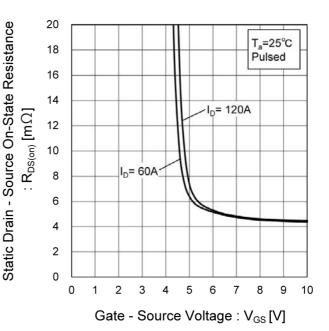


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

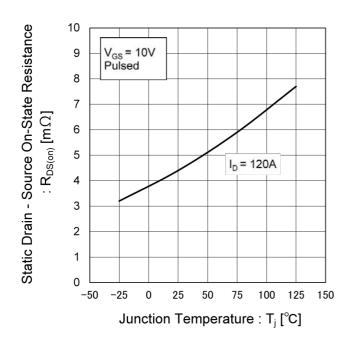


Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current (I)

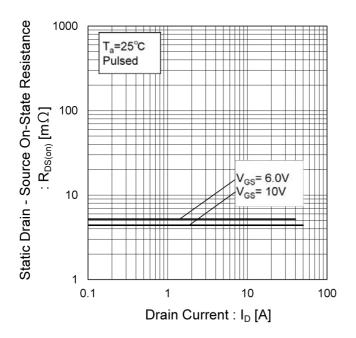


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

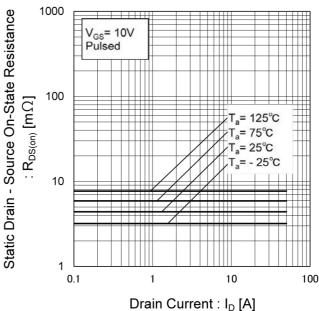


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

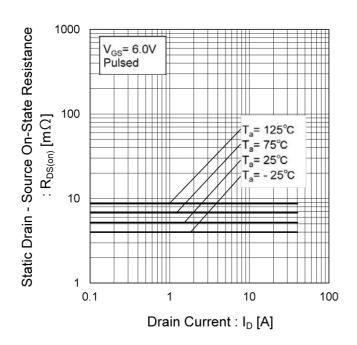
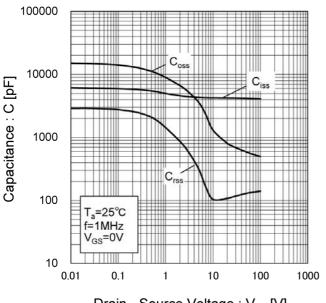


Fig.17 Typical Capacitance vs.

Drain - Source Voltage



Drain - Source Voltage : $V_{DS}[V]$

Fig.18 Switching Characteristics

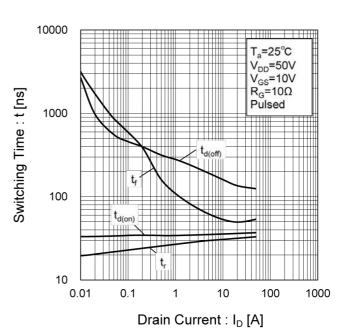


Fig.19 Dynamic Input Characteristics

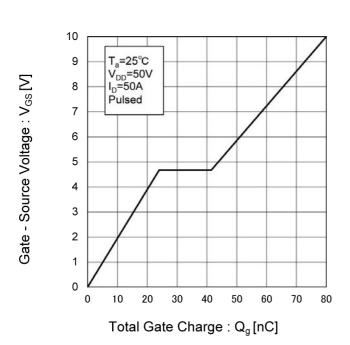
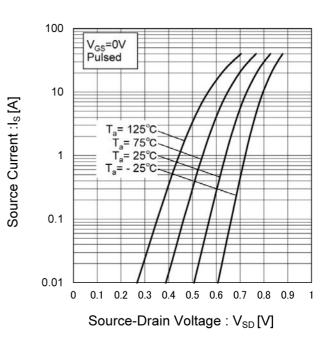


Fig.20 Source Current vs.

Source Drain Voltage



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

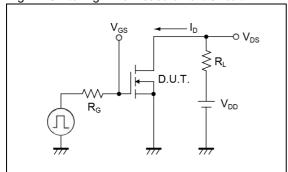


Fig.2-1 Gate Charge Measurement Circuit

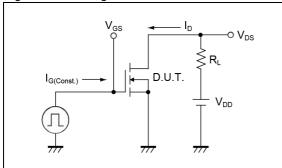


Fig.3-1 Avalanche Measurement Circuit

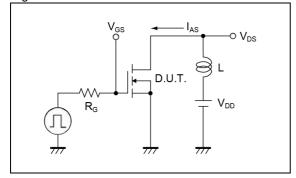


Fig.1-2 Switching Waveforms

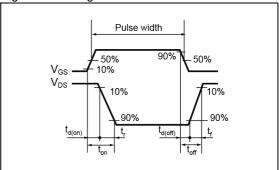


Fig.2-2 Gate Charge Waveform

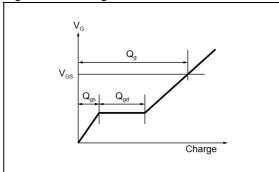
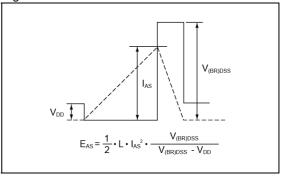
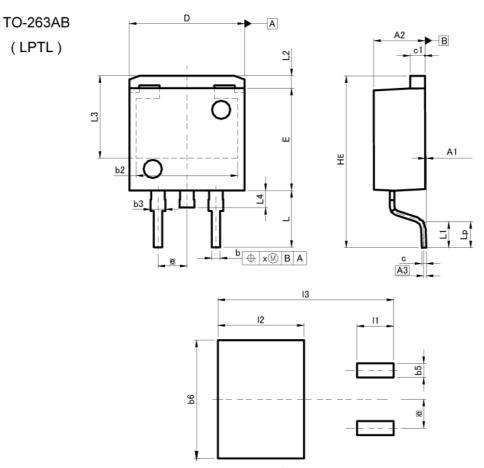


Fig.3-2 Avalanche Waveform



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

| DIM | MILIM | MILIMETERS | | HES |
|-----|----------------|------------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| A1 | 0.00 | 0.30 | 0.000 | 0.012 |
| A2 | 4.30 | 4.70 | 0.169 | 0.185 |
| A3 | 0.: | 25 | 0.0 | 10 |
| b | 0.68 | 0.98 | 0.027 | 0.039 |
| b2 | 8.9 | 90 | 0.3 | 50 |
| b3 | 1.14 | 1.44 | 0.045 | 0.057 |
| С | 0.30 | 0.60 | 0.012 | 0.024 |
| c1 | 1.10 | 1.50 | 0.043 | 0.059 |
| D | 9.80 | 10.40 | 0.386 | 0.409 |
| E | 8.80 | 9.20 | 0.346 | 0.362 |
| е | 2. | 2.54 0.100 | | 00 |
| HE | 14.80 | 15.40 | 0.583 | 0.606 |
| L | 4.70 | 5.30 | 0.185 | 0.209 |
| L1 | 2.10 | 2.70 | 0.083 | 0.106 |
| L2 | 1, | 10 | 0.0 | 43 |
| L3 | 7.: | .25 0.285 | | 85 |
| L4 | 1. | 50 | 0.0 | 59 |
| Lp | 2.60 | 2.00 | 0.102 | 0.079 |
| х | (- | 0.25 | - | 0.010 |

| DIM | MILIM | ETERS | INC | HES |
|-----|------------------|-------|----------------|-------|
| DIM | MIN | MAX | MIN | MAX |
| b5 | | 1.23 | (*) | 0.049 |
| b6 | | 10.40 | (- | 0.409 |
| 11 | 12 | 3.20 | = | 0.126 |
| 12 | \$ 75 | 7.55 | - | 0.297 |
| 13 | 58 | 15.40 | - | 0.606 |

Dimension in mm/inches



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|---------|----------|------------|----------|
| CLASSⅢ | CLASSⅢ | CLASS II b | CL ACCTI |
| CLASSIV | CLASSIII | CLASSⅢ | CLASSIII |

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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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